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Collective dipole-dominated doping of monolayer MoS₂: orientation and magnitude control via the supramolecular approach

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ABSTRACT

Molecular doping is a powerful, tuneable and versatile method to modify the electronic properties of two-dimensional (2D) transition metal dichalcogenides (TMDCs). While electron transfer is an isotropic process, dipole-induced doping is a collective phenomenon in which the orientation of the molecular dipoles interfaced to the 2D material is known to be key to modulate and boost this electronic effect, despite it has not yet been demonstrated. Here we report a novel method towards the molecular functionalization of monolayer MoS₂ relying on the molecular self-assembly of metal phthalocyanine (MPc) and the orientation-controlled coordination chemistry of axial ligands. We have demonstrated that the subtle variation of position and type of functional groups exposed on the pyridinic ligand, yields a molecular dipole with programmed magnitude and orientation which is capable to strongly influence the opto-electronic properties of monolayer MoS₂. In particular, experimental results revealed that both p- and n-type doping can be achieved by modulating the charge carrier density up to $4.8 \times 10^{12}/\text{cm}^2$. Density functional theory calculations showed that the doping mechanism is primarily resulting from the effect of dipole-induced doping rather than charge transfer between MoS₂ and molecules. Our strategy to dope TMDCs is a highly modulable and robust, and it enables to enrich the functionality of 2D materials-based devices for high-performance applications in opto-electronics.

MAIN TEXT

Two-dimensional (2D) transition metal dichalcogenides (TMDs) have been the subject of intensive studies during the last decade because of their unique physico-chemical properties.^[1] The most representative member of the family, MoS₂, is a semiconductor possessing a layer-dependent tunable bandgap (1.2 eV for bulk material and 1.9 eV for monolayer), high $I_{\text{on}}/I_{\text{off}}$ ratio, large charge carrier mobility, and fast light response. Such unique features make MoS₂ a promising component for a variety of applications from (opto)electronics to valleytronics.^[2] In particular, these properties open up a multitude of opportunities for the construction of high-performance ultra-thin heterojunction devices, e.g. p-n junctions and photodetectors.^[3] Interestingly, the combination of organic molecules with TMDs was proven to be a versatile approach to tune the properties of the latter component via the 2D material's doping,^[4] defect engineering,^[5] device performance improvement,^[6] etc..

Metal phthalocyanines (MPcs), an established family of symmetrical macrocycles comprising four iminoisoindoline units interacting with central metal ions, have been explored as molecular pigments for over a century. More recently, the applications of MPcs expanded to field-effect transistors, photovoltaic devices, phototherapies and catalysis by taking full advantage of the chemically modifiable structure which allows the tuning of many fundamental properties such as electron/hole conduction, light absorption and emission, etc.^[7] The anionic aromatic ring tightly bonded with a cation center renders the conformationally planar MPcs highly stable against decomposition.^[7b] Moreover, most MPcs form type II band alignment with monolayer

and few-layer MoS₂.^[8] Thus, they are appropriate candidates to functionalize ultra-thin MoS₂ films, eventually via the formation of Van der Waals organic-inorganic heterostructures. This type of heterostructures has been proved to feature charge transfer from the LUMO of MPc to the conduction band of MoS₂, resulting in doping in field-effect transistors (FETs),^[9] Raman enhancement,^[10] photoresponse improvement,^[11] etc.

The combination of MPcs and MoS₂ has been the subject of previous studies, all of them focused on either the charge transfer mechanism or the influence of the type of metal core on the energy of LUMO ($2e_g$ orbital) in the complex.^[8-10, 12] Surprisingly, the exploration of axially functionalized MPcs has never been addressed. Coordination chemistry offers a broadest variety of functionalization solutions to decorate 2D materials beyond the two-dimensional space through the bonding of organic ligands to metal ions. Pyridine, being one among the most common ligands, enables a coordination involving the hybridization of its sp^2 electron lone pair to metal d orbitals, yielding a decrease of the $18-\pi$ aromaticity in MPcs, ultimately pulling the metal core out of the plane.^[13] The axial pyridinic ligand is always standing perpendicular to the basal plane of the Pc ring. In fact, the four planar coordination sites in octahedral metal d orbitals are already occupied by four nitrogen atoms in the pyrrole rings, thus, the only possibilities for pyridine ligands to be coordinated are in the axial fifth and/or sixth sites. Previous works have shown that MPcs self-assemble on MoS₂ or graphite by forming supramolecular mono-molecular thick arrays with the Pc ring lying parallel to the basal plane of the substrate.^[10, 14] In this regard, one can consider that once axial

ligands are coordinated onto self-assembled MPcs already coupled with MoS₂, they form ordered molecular arrays that are perpendicular to the MoS₂ /MPc heterojunction plane. When the axial ligands possess non-negligible dipole moments, these perpendicular molecular arrays could be translated as aligned molecular dipoles which are considered as a main factor to affect physical properties of MoS₂ in molecular doping.^[4b] In this framework, it is essential to exploit the chemical programmability of axial ligands under the context of atomic-thin heterostructures.

In this work, we propose a radically novel strategy to molecular doping of monolayer MoS₂ by using MPcs as self-assembled template to grow ligands featuring relatively large molecular dipoles oriented perpendicularly the basal plane of the 2D material. Our approach consists of two-step functionalization: 1) Growth from solution of an ultra-thin self-assembled MPcs onto monolayer MoS₂; 2) Coordination of functionalized pyridines (fPys) onto the MoS₂/MPc heterostructures (Scheme 1a) in the vapor phase. In particular, we use two prototypical MPcs, i.e. zinc phthalocyanine (ZnPc) and cobalt phthalocyanine (CoPc) with distinct d-electron fillings (Co: d⁷ and Zn: d¹⁰). For fPy, we have chosen fluorine and amine substituted pyridines in different positions of the aromatic ring to ensure marked variation of the dipole moment magnitude and orientation, namely 3,5-difluoropyridine (3,5-FP), 3-fluoropyridine (3-FP), 2-fluoropyridine (2-FP) and 4-aminopyridine (4-AP). The chemical structures of MPcs and fPys are depicted in **Scheme 1a** and **1b**, respectively. Our approach holds three major advantages compared to the state-of-the-art: First, the low-temperature nature of the process of coordination of the central metal with the pyridine avoids occurrence of

re-aggregation of the MPcs thereby guaranteeing their planar packing onto monolayer MoS_2 ,^[10] second, the use of a vapour phase deposition of the substituted pyridines means that the MPcs are not subjected to re-dissolution, thus guaranteeing the largest amount of fPy to be coordinated; third, the orientation of the ligand dipole in the fPy-MPc complex is ruled by geometric control of coordination bond, in full absence of π - π packing between fPy ligand and adjacent Pc rings which typically takes place in solution phase processes. In our textbook experiment, we found that simple variation of the magnitude and the orientation of ligand dipoles can be attained by changing the type and position of substitution groups in pyridine rings resulting in a tuneable modulation of charge carrier density in monolayer MoS_2 /MPc heterostructures either via p- or n-doping. Both experimental and theoretical results provided unambiguous evidence for the pronounced effect of molecular dipole generated by axially bonded ligand, paving the way for controllable molecular doping of 2D materials.

Scheme 1. (a) Illustration of two-step functionalization of ligand-coordinated MoS_2 /MPc heterojunction.

Chemical structure of **(b)** MPcs and **(c)** fPys used in this work.

To understand the electronic effect of axially functionalized MPc on MoS₂, we first gained qualitative insight into the effects of axial ligands on the monolayer MoS₂. **Figure 1a** and **b** show the AFM images of monolayer MoS₂ before and after the formation of 4-AP axial ligand on ZnPc. The pristine monolayer MoS₂ was found to be 0.73 nm thick, in agreement with the literature.^[15] After the functionalization, the average height of the adlayer increased significantly thereby reaching 2.07 nm. Such an increase in thickness resulted from the physisorption of ZnPc, the binding of 4-AP and the out-of-plane displacement of zinc atom after coordination. The interfacial distance between ZnPc and MoS₂ was previously reported being ~ 0.37 nm,^[16] the ZnPc monolayer thickness amounting to ca. 0.40 nm, the height of 4-AP being ca. 0.50 nm, and the displacement of Zn atom consisting of 0.05 nm.^[13] We found that the difference of vertical distance before and after the functionalization amounts to 1.34 nm (**Figure 1d**), thus matching perfectly with the expected molecular configuration in **Scheme 1a**. High-resolution AFM images, as those displayed in **Figure 1c**, revealed that the morphology of self-assembled ZnPc/4-AP on MoS₂ consists of long parallel stripes with a width ranging between 12 and 20 nm. Such result is in line with previous STM observations with MPcs physisorbed onto MoS₂ forming stripes of closely packed two or more molecular rows with a gap between the stripes of 0.78 nm.^[14b] The periodic structure also confirms that the coordination of ligands using our method does not destroy the self-assembled motif of ZnPc on MoS₂, enabling the edge-on packing of the pyridines. Raman spectroscopy also confirmed the successful functionalization of 4-AP ligand (**Figure 1e**). While a group of peaks appeared at high

wavenumber as a result of the formation of MoS₂/ZnPc heterostructure, corresponding to the vibration mode from Pc ring,^[17] after the coordination of 4-AP, these features were preserved and combined with intensity enhancement at ~1405 cm⁻¹ and 1510 cm⁻¹. The latter two peaks can be ascribed to the amino group and pyridine, respectively.^[18] In all the combination of MPcs and fPys, we have observed similar signatures. XPS spectra of N 1s (e.g. see **Figure 1f**) also validated the efficient ligand functionalization. The proportion of nitrogen linked with metal increased from 36.95% (approx. 3 out of 8 nitrogen atoms) to 39.19% (approx. 3.6 out of 9 nitrogen atoms) after the coordination with 4-AP, indicating a 88.17% functionalization yield. The Mo 3d and S 2p spectra have demonstrated evident shifts according to different fPy functionalization, which could be found in **Figure S1**.

Figure 1. Topographic AFM image of (a) pristine monolayer MoS₂ and (b) monolayer MoS₂/ZnPc/4-AP, (c) the latter also on the sub-μm scale. (d) Height profile of monolayer MoS₂ and monolayer MoS₂/ZnPc/4-AP. (e) Raman spectra of monolayer MoS₂, monolayer MoS₂/ZnPc, and monolayer MoS₂/ZnPc/4-AP. (f) N 1s XPS spectra of monolayer MoS₂, monolayer MoS₂/ZnPc, and monolayer MoS₂/ZnPc/4-AP.

MoS₂/ZnPc/4-AP in high wavenumber range. **(f)** XPS spectra of N 1s of monolayer MoS₂, monolayer MoS₂/ZnPc, and monolayer MoS₂/ZnPc/4-AP.

After confirming the effective functionalization, we explored how the axial ligands approach influences the electronic properties of MoS₂. We have fabricated back-gate, top-contact FETs with monolayer MoS₂ as channel material, as portrayed in **Figure 2a**. After the formation of self-assembled MPcs, we have observed a large shift of transfer curve (I_{ds} - V_g) to the positive direction (**Figure 2b and c**). Such evidence can be attributed to the formation of p-n junctions, in agreement with previous studies.^[9, 11b] By further coordinating the fPys, we have observed shifts in two opposite directions: for 3,5-FP and 3-FP, the I_{ds} - V_g curves shift to positive voltages while for 2-FP and 4-AP, the curves shift to the negative direction.

Figure 2. Electronic properties of ligand functionalized monolayer MoS₂. **(a)** Device structure of monolayer MoS₂ functionalized with MPc/fPy. **(b)** Comparison of transfer curves of MoS₂/ZnPc heterojunction coordinated with ligands. **(c)** Comparison of transfer curves of MoS₂/CoPc heterojunction coordinated with ligands.

The shift could be quantified by calculating the threshold voltage change (ΔV_{th}) in the transfer curve, as shown in **Figure 3a**. This value is known to correlate linearly with the charge carrier density change Δn by molecular doping in a semiconducting material, which could be solved with the following equation:

$$\Delta n = \frac{C_{ox} \Delta V_{th}}{e} = \frac{\epsilon_{ox} \Delta V_{th}}{t_{ox} e} \quad (1)$$

where Δn is the change in electron (negative charge) density, C_{ox} is the capacitance per unit area of 270 nm SiO₂, e is the elementary charge, and ϵ_{ox} is the dielectric constant of SiO₂, ΔV_{th} is the change of threshold voltage and t_{ox} is the thickness of SiO₂.

The calculated results are presented in **Figure 3b** in solid circles. We found that for MoS₂/ZnPc, ligand functionalization enables to modulate the carrier density in MoS₂ from $-3.0 \times 10^{12}/\text{cm}^2$ in 3-FP to $1.8 \times 10^{12}/\text{cm}^2$ in 4-AP, while for MoS₂/CoPc, the modulation ranges from $-3.5 \times 10^{12}/\text{cm}^2$ in 3-FP to $5.32 \times 10^{11}/\text{cm}^2$ in 4-AP, with respect to the reference case of MoS₂/MPc. The magnitude of the changes is surprisingly high, being comparable to the doping of ZnPc and CoPc on MoS₂ which amounts $1.8 \times 10^{12}/\text{cm}^2$ and $2.1 \times 10^{12}/\text{cm}^2$, respectively. Considering that the major charge carriers in MoS₂ are electrons, it is then obvious to conclude that 3,5-FP and 3-FP decrease in electron density in MoS₂/MPc, inducing p-doping, whereas 2-FP and 4-AP increase the electron density, inducing n-doping. The overall doping has also been observed to be dependent on the time of the fPys coordination. This time-dependent study also enables us to define the optimal functional time for each ligand to achieve the maximum doping effect on the MoS₂/MPc heterostructure. Detailed discussions are presented in **Figure S3** (Supporting Information). The tuneable either p- or n-type doping exhibits considerable changes in carrier densities in MoS₂/ZnPc which are comparable to effective molecular doping reported in the literature, being of the same orders of magnitude.^[9, 19] The combination effect of ZnPc and 3,5-FP could decrease

the electron density by $3.5 \times 10^{12}/\text{cm}^2$, whereas the combination of CoPc and 4-AP could yield to an increase the electron density by $1.5 \times 10^{12}/\text{cm}^2$. The largest difference in electron density achieved with different binding ligands, namely 3,5-FP and 4-AP, reaches values as high as $4.8 \times 10^{12}/\text{cm}^2$ for ZnPc and $4.1 \times 10^{12}/\text{cm}^2$ for CoPc. These values are markedly larger than the values attained by using unsubstituted MPcs as dopants of monolayer MoS₂.^[9, 11] Blank experiments carried out by interfacing fPys directly on MoS₂ via physisorption, in absence of the MPcs templating layer, revealed a much weaker effect after thermal annealing (at 95 °C for 3,5-FP, 3-FP, 2-FP and 200 °C for 4-AP) as a result of molecular desorption (**Figure S2**). Moreover, all fPys showed mild n-doping effect with V_{th} shift by 3 to 4 V ($\Delta n = 2.4 \times 10^{11}/\text{cm}^2$ to $3.2 \times 10^{11}/\text{cm}^2$), in stark contrast to our observations in the n- and p-type doping in the MoS₂/MPc/fPy hybrid heterostructure, especially when 3,5-FP and 3-FP are used as ligands. Thereby, the observed doping, which is strongly affected by the orientation of the dipoles, should be ascribed to the effect of the MPc-fPy coordination, in contrast to the random physisorption of fPys on MoS₂.

Figure 3. (a) Typical transfer curve of MoS₂/ZnPc and MoS₂/ZnPc/3,5-FP showing the calculation of ΔV_{th} before and after ligand functionalization. (b) Charge carrier density shift in monolayer MoS₂ after ligand functionalization of fPys on MPc obtained from FET measurements with comparison to the theoretical results calculated from work function analysis.

In order to investigate the role of ligand functionalized MPcs in modulating the charge carrier density, we have carried out density functional theory (DFT) calculations. It is indeed notorious that the component of molecular electric dipoles perpendicular to the surface of 2D materials exert a polarization capable of shifting the surface work function, hence inducing a local doping.^[20] Accordingly, we have calculated the theoretical work function (ϕ_{th}) of MoS₂/MPc/fPy heterostructures in conjunction to the axial dipole moment of these heterostructures and the dipole induced electrostatic potential of isolated molecules at vacuum level (E_p) in order to trace the relative changes in ϕ_{th} of MPc/fPys. All MPc/fPys form type II heterostructures with MoS₂, irrespective of the type of axial ligands, as emphasized in previous works,^[16,17] wherein the HOMO of MPc/fPys is located within the band gap of MoS₂ monolayer (see **Figures S4-S6**). Theoretical values for the work function (ϕ_{th}) of MoS₂/ZnPc and MoS₂/CoPc are found to be 5.13 eV and 5.18 eV respectively, in close agreement with the experimental observations (see **Figure 4** and **Table 1**). Upon addition of the axial ‘un-functionalized’ pyridine (Py) ligand to MPc, the work function was found to increase. This is because MoS₂/MPc/Py features an axial dipole moment (perpendicular to and directed towards the basal plane of MoS₂ surface, note as dipole 1) originating from the ligand induced metal-N coordination bonding. When the axial pyridine ligand has functional groups on the aromatic ring, additional changes in the work function can be predicted: MoS₂/MPc/3,5-FP and MoS₂/MPc/3-FP showed relatively higher ϕ_{th} values than MoS₂/MPc/Py, whereas MoS₂/MPc/2-FP and MoS₂/MPc/4-AP displayed comparatively lower ϕ_{th} values. These relative changes in work function of

MoS₂/MPc/fPys with respect to MoS₂/MPc/Py follow the variation in the net dipole moment (axial component, note as dipole 2) of the functionalized molecules. To comprehend the relative variation in net dipole moment due to pyridine functionalization and its subsequent impact on the observed work function changes, we define dipole 2 as the difference between the net dipole moments of functionalized pyridine molecules (MoS₂/MPc/fPys) and dipole 1, which is the net dipole moment of un-functionalized pyridine (MoS₂/MPc/Py). Dipole 2 therefore quantifies the contribution of functional groups present on the pyridine ligand to the net dipole moment of MoS₂/MPc/fPys, wherein a positive (negative) value of dipole 2 partially cancels (add to) the contribution of dipole 1. The net dipole moments of MoS₂/MPc/3,5-FP and MoS₂/MPc/3-FP are lower than that of MoS₂/MPc/Py, as the relative positioning of fluorine atoms in 3,5-FP and 3-FP generates a dipole electric field that is directed away from the MoS₂ surface (positive dipole 2), thereby partially cancelling the field induced by the metal-N coordination. In contrast, the net dipole moments of MoS₂/MPc/2-FP and MoS₂/MPc/4-AP were found being higher compared to MoS₂/MPc/Py, because the normal component of the dipole carried by the functional groups adds in phase to the metal-N coordination dipole, both being directed towards the surface (see **Figure S7**). Furthermore, as presented in **Figure 4**, the variation in the dipole moment of MoS₂/MPc/fPy heterostructures and the associated work function changes are proportional to the dipole induced electrostatic potential of isolated molecules at their vacuum level (E_p). Because of the atomic thickness of monolayer MoS₂, the electric field generated by aligned molecular dipole could result in a large

charge carrier modulation and thus promote doping, analogously to a local electric gate.^[4a] Hence, with reference to MoS₂/MPc/Py, a relative p-doping could be predicted for MoS₂/MPc/3,5-FP and MoS₂/MPc/3-FP that showed a reduced normal dipole moment, while a relative n-doping would be expected for MoS₂/MPc/2-FP and MoS₂/MPc/4-AP yielding an increased dipole moment. Photoelectron spectroscopy measurements in air (PEYA) in **Figure S8** confirmed that experimentally, the work function values shift with the same trends observed in DFT calculations, with 4-AP reducing the work function value to 5.11 eV and 3,5-FP increasing the work function up to 5.30 eV. The great modulation of work function revealed that the Fermi level of monolayer MoS₂ is largely influenced by the ligand functionalization with much more important contribution coming from the molecular dipole.

Figure 4. Calculated work function of MoS₂/MPc/fPys for (a) M=Zn, and (b) M=Co. The ϕ_{exp} stands for experimental work function values measured by PhotoElectron Yield counter operating in Ambient conditions (PEYA) which are presented in Figure S8. The work function trends follow the computed dipole induced electrostatic potential (E_p) of the isolated molecules at vacuum level.

Molecule	ϕ_{exp} (eV)	ϕ_{th} (eV)	D_{total} (D)	E_p (eV)
MoS₂/ZnPc/fPys				
MoS ₂ /ZnPc	5.22	5.130	-1.333	-0.136
MoS ₂ /ZnPc/Py	5.24	5.171	-7.465	-0.264

MoS ₂ /ZnPc/3,5-FP	5.28	5.207	-5.431	-0.233
MoS ₂ /ZnPc/3-FP	5.26	5.205	-6.455	-0.249
MoS ₂ /ZnPc/4-FP	--	5.206	-5.767	-0.240
MoS ₂ /ZnPc/2-FP	5.19	5.186	-7.924	-0.276
MoS ₂ /ZnPc/4-AP	5.14	5.147	-10.661	-0.326
MoS₂/CoPc/fPys				
MoS ₂ /CoPc	5.27	5.18	-1.522	-0.129
MoS ₂ /CoPc/Py	--	5.20	-6.679	0.240
MoS ₂ /CoPc/3,5-FP	5.30	5.24	-4.957	-0.223
MoS ₂ /CoPc/3-FP	5.28	5.22	-6.006	-0.241
MoS ₂ /CoPc/4-FP	--	5.23	-5.109	-0.228
MoS ₂ /CoPc/2-FP	5.20	5.18	-7.218	-0.264
MoS ₂ /CoPc/4-AP	5.11	5.14	-9.985	-0.295

Table 1. Work function and dipole moment of MoS₂/MPc/fPy systems. ϕ_{th} : work function of MoS₂ monolayer functionalized with MPc/fPys. ϕ_{exp} : work function values measured by PhotoElectron Yield counter operating in Ambient conditions (PEYA) which are presented in Figure S8. D_{total} : total dipole moment of MoS₂/MPc/fPy in Debye, negative sign indicates dipole moment directed towards basal plane of MoS₂ surface. E_p : Dipole induced electrostatic potential (in eV) of isolated ligand at vacuum level. Additional calculations were performed on MoS₂/MPc/4-fluoropyridine (4-FP) for consistency in ϕ - Dipole moment trends.

Not only the electrical properties in MoS₂ are strongly influenced by ligand-induced dipoles, but also the optical properties are greatly affected. The direct bandgap at K point enables strong photoluminescence (PL) emission in monolayer MoS₂. Typical PL spectra of monolayer MoS₂ can be found in **Figure 5a**. We could find two major peaks originated from spin-orbit splitting of transition metal, one at lower energy, denoting A exciton peak, and the other, the B exciton peak, at higher energy. Referring to the literature,^[21] A exciton peak could be split into two components after Lorentzian fitting, which are noted as X⁻ at around 1.83 eV, and X at around 1.87 eV. The ability of binding an extra electron to neutral exciton X (one electron binds with one hole) gives rise to the negative trion X⁻ with binding energy of around 40 meV in room temperature, when the charge carrier density in

monolayer MoS₂ is in excess of electrons. Hence, the switching of intensity of trion and exciton mirrors the balance between electrons and hole in MoS₂ sheets, in other words, the doping level in MoS₂. We are able to quantify the trion weight γ by

$$\gamma = \frac{I_{X^-}}{I_{\text{total}}} = \frac{I_{X^-}}{I_{X^-} + I_X} \quad (7)$$

As is demonstrated in the left panel in **Figure 5a**, the electronic coupling of ZnPc on MoS₂ caused decrease in trion from 0.71 to 0.31, implying compensating of excessive negative charges in pristine MoS₂, inducing p-dope decreasing the electron. After coordinating fPys, 3,5-FP and 3-FP yielded a further decrease of trion weight (middle panel in **Figure 5a**), whereas 2-FP and 4-AP brought back the recombination of trion (right panel in **Figure 5a**). The quantified values of trion weight are plotted in **Figure 5b**. Unfunctionalized pyridine whose dipole moment induced by the functional groups is considered to be 0 showed trion weight between 3-FP and 2-FP after coordinating with ZnPc, indicating that the inversion of sign of dipole 2 could alternatively influence the regulation of trion weight. Similarly, in **Figure 5c** and **d**, despite the severe suppression of the formation of trions after doping with CoPc, the coordination of fPys led to a similar trend observed for ZnPc, but in a smaller value range.

Figure 5. Photoluminescence spectra of (a) MoS₂/ZnPc and (c) MoS₂/CoPc coordinated with fPys. (b) and (d) average trion weight of each ligand coordinated heterojunction with ZnPc and CoPc, respectively.

To exclude the doping originated from physisorption of pyridines and solvents, we performed control experiments without MPcs with the same experimental procedures whose results are portrayed in **Figure S9**. In particular, similar results were found when doing blank tests with MoS₂ based FETs coated by fPys, in absence of templating MPcs. Upon thermal annealing treatments, the fPys were found to desorb leading to negligible doping effects of the MoS₂. The only small amount of fPys remained on the surface possess a random geometrical configuration without alignment of molecular dipoles, thus eliminating the molecular gating effect induced by a collective process. The trion weight can be translated to charge carrier density by means of the mass action model. We found approximate values as in FET analysis (shown in **Table S1**), confirming that molecular dipole induced doping by fPys is very little affected by the optical properties of MPcs.

Furthermore, Raman vibrations of monolayer MoS₂ were also found to be sensitive to the coordination of fPys. Two main Raman modes of undoped MoS₂ were measured, i.e. the out-of-plane E_{2g}¹ mode at ~386 cm⁻¹ and the in-plane A_{1g} mode at 405 cm⁻¹. Compared to the bare MoS₂, the addition of MPc resulted in small blueshift in A_{1g} peak and nearly no change in E_{2g}¹ peak (**Figure S10**). It is reported in the literature that doping could affect the A_{1g} mode in higher extent than E_{2g}¹ mode, thus yielding shifts in peak position. The redshift corresponds to the increase in electron concentration which softens the Raman vibration, and the blueshift corresponds to decrease of electron concentration which hardens the vibration.^[19] The ligands, accordingly, led to non-negligible shift in A_{1g} modes. As shown in **Figure 6a**, 3,5-FP and 3-FP blueshifted the A_{1g} peak for 0.402 cm⁻¹ and 0.120 cm⁻¹ respectively, indicating p-doping. 2-FP and 4-AP induce redshift of 0.213 cm⁻¹ and

0.564 cm^{-1} , reflecting n-doping. The observed effect is in perfect agreement with FET analysis, DFT calculation and PL measurements providing an unambiguous evidence that MPcs p-dopes the pristine MoS₂. The average Raman shift of A_{1g} peak between different fPy ligands could be as much as 0.966 cm^{-1} , while the E_{2g} peak remained constant under the influence of molecular dipoles. (**Figure 6b**). The full width at half maximum (FWHM) of A_{1g} peak was also found to be broadened by n-doping and sharpened by p-doping, demonstrated in **Figure 6b**. This could be explained by enhanced electron-phonon coupling of A_{1g} mode by increasing the electron density in MoS₂. The variation of FWHM could attain $\sim 1 \text{ cm}^{-1}$ by changing the functionalized ligand.

Figure 6. (a) Raman spectra of pristine MoS₂ and functionalized with ZnPc/fPys. (b) Plot of the shift in E_{12g} mode and A_{1g} mode, and the variation of full width of half maximum (FWHM) of A_{1g} peak upon the functionalization by different fPy ligands.

CONCLUSIONS

In summary, we have demonstrated a new strategy for doping 2D semiconductors by combining supramolecular self-assembly at surfaces, coordination chemistry and molecularly driven electrical gating. Aligned molecular dipoles having a precise

orientation with respect to the basal plane of the MoS₂ surface were generated by taking advantage of the versatile functionalization of pyridine molecules and the geometry-controlled ligand binding direction in zinc and cobalt phthalocyanines. Electrical analysis, spectroscopic measurements and DFT calculations confirmed that not only charge transfer between axially functionalized MPc and monolayer MoS₂ participate in the tuning of properties, but also that the aligned dipole moments generated by pyridinic ligands play a much more important role in controlling the either n- or p-type doping of MoS₂ by modulating the charge carrier density up to $4.8 \times 10^{12}/\text{cm}^2$. Optical properties, such as exciton/trion switching and Raman features were found to be largely influenced by the molecular dipoles. Our results revealed how the variation of molecular dipole could strongly affect both the electrical and optical properties of underneath substrate material. A brand-new concept in realizing the controllable doping by organic molecules without the need of cumbersome synthesis or functionalization with complex chemical reactions has been proposed. The large magnitude of this doping effect is guaranteed by the collective nature of the dipole effect induced by the simultaneous alignment of a huge number of molecules yielding a nonlocal macroscopic effect. Our approach of molecularly tuned dipole induced doping is highly modifiable and generally applicable to other 2D materials, thereby opening new avenues for enhancing the performances of 2D materials for applications in optoelectronics.

EXPERIMENTAL SECTION

Sample preparation. Monolayer MoS₂ were mechanically exfoliated from commercially available molybdenite crystals (Furuchi, Japan) using the scotch tape method and transferred on thermally oxidized heavily *n*-doped silicon substrates (Fraunhofer Institute IPMS, $\rho_{\text{Si}} \sim 0.001 \text{ } \Omega \cdot \text{cm}$, $t_{\text{ox}} = 270 \text{ nm}$). Their thickness was monitored by optical microscope combined with Raman spectroscopy and Atomic Force Microscopy (AFM). The samples were thermally annealed at 200 °C inside a vacuum chamber to desorb atmospheric adsorbates. ZnPc and CoPc are purchased from Merck. The MoS₂/MPc hybrids were realized by immersing monolayer MoS₂ into 0.5 mM MPc in anhydrous solution, then rinsed vastly and thermally annealed in nitrogen to remove aggregates and evaporate solvents. To avoid the desorption of MPc on MoS₂ when reacting with ligands in solvent environment, the coordination of pyridinic ligand (TCI Chemicals) is reacted in vapor phase where 50 μL of pure pyridine was added in a 60 mL closed beaker containing the MoS₂/MPc heterostructure on Si/SiO₂ chip. The whole beaker is heated up to an ad hoc temperature (85 °C for 3,5-FP, 3-FP, 2-FP and 175 °C for 4-AP) to form pyridine vapours to enable the contact with MPc. The optimal functionalization time was defined by time-dependent study of the functionalization; it amounts to 25 min for 3,5-FP, 3-FP, 4-AP, and 15 min for 2-FP. Subsequently, post thermal-annealing treatments (95 °C for 3,5-FP, 3-FP, 2FP and 200 °C for 4-AP) for 20 min is performed in order to remove physisorbed pyridines from the surface. The functionalized samples are measured after being cooled down to room temperature. All the reactions were done in a nitrogen-filled glovebox to exclude the effect from O₂ and

H₂O in air.

Device fabrication and electrical characterization. As-exfoliated MoS₂ monolayer were coated with 2 layers of PMMA (Allresist, 600K/ 950K) immediately after exfoliation to avoid air exposure. Top-contact (80 nm Au) field-effect transistors were fabricated by standard E-beam lithography and lift-off in warm acetone in glovebox. All devices were annealed under vacuum at 200°C overnight to remove absorbents. The characterization of device performance was realized by Keithley 2636A under N₂ atmosphere.

Raman spectroscopy. Raman and Photoluminescence spectra were carried out in inert atmosphere (N₂) by Renishaw inVia spectrometer equipped with 532 nm laser in a nitrogen-filled sealed holder (Linkam). Samples were mounted in the glovebox and immediately measured after annealing or after molecule deposition to avoid exposure to contaminant chemicals. The excitation power was kept below 1 mW to avoid local heating damage effects. The wavenumber (energy) resolution was ~1 meV.

AFM measurement. AFM imaging was performed by means of a Bruker Dimension Icon set-up operating in air, in tapping mode, by using tip model TESPA-V2 (tip stiffness: k=42 N/m).

XPS measurements: Commercial CVD-grown triangle monolayer MoS₂ on Si/SiO₂ (6Carbon Technology (Shenzhen)) was employed to study the surface chemistry of MoS₂, MoS₂/MPc and MoS₂/MPc/fPy. XPS analyses were carried out with a Thermo Scientific K-Alpha X-ray photoelectron spectrometer with a basic chamber pressure of $\sim 10^{-9}$ mbar and an Al anode as the X-ray source (x-ray radiation of 1486 eV). Spot sizes of 400 μm and pass energies of 200.00 eV for wide energy scans and 10.00-20.00 eV for scans were used.

Photoelectron spectroscopy measurement in air: Commercial CVD-grown triangle monolayer MoS₂ on Si/SiO₂ (6Carbon Technology (Shenzhen)) was employed to measure the experimental work functions of MoS₂, MoS₂/MPc and MoS₂/MPc/fPy by PhotoElectron Yield counter operating in Ambient conditions (PEYA), using a AC-2 Photoelectron Spectrometer (Riken-Keiki Co.). The ambient photoelectron spectroscopy measurements were performed by sampling in each measurement an area of about 4 mm² (beam size) with an ultraviolet (UV) incident light power of 300 nW with a counting time of 10 seconds per point.

Computational details. All DFT calculations were performed with the projector-augmented wave (PAW) basis set, as implemented in the VASP code.^[22] The exchange and correlation effects are treated with the Perdew–Burke–Ernzerhof (PBE) functional,^[23] incorporating dipole moment correction along the ‘c’ axis (Z direction and perpendicular to the MoS₂ surface) and dispersion forces by Grimme correction

(PBE+D2),^[24] with a kinetic energy cutoff of 550 eV and using a Monkhorst-Pack mesh of $2 \times 2 \times 1$ for the Brillouin zone (BZ) integration. All MPC/fPys were adsorbed on a 10×10 supercell of MoS₂ monolayer with the vacuum space was set to be 25 Å to avoid the interaction with periodic images. Geometries of MoS₂/MPC/fPy heterostructures were fully optimized prior to calculation of work functions. Work function (φ) of heterostructures is calculated as difference of Fermi energy (E_f) and the electrostatic potential at vacuum level (E_p). Fermi level (E_f) is set to the energy of valence band maximum for MoS₂/ZnPc/fPys and for MoS₂/CoPc/fPys, which are open shell systems, E_f is set to the maximum energy of the valence band with doubly occupied electrons ignoring the energy state of the unpaired electron localized on Co.

AUTHOR INFORMATION

PS and YW conceived and coordinated the work. YW worked on sample preparation, device fabrication, optical and electrical characterization. YW analysed the data. SMG & AS did the modelling work, under the supervision of DB. YW and PS wrote the paper with all the authors contributing to the discussion and preparation of the manuscript.

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